

## GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz



### Typical Applications

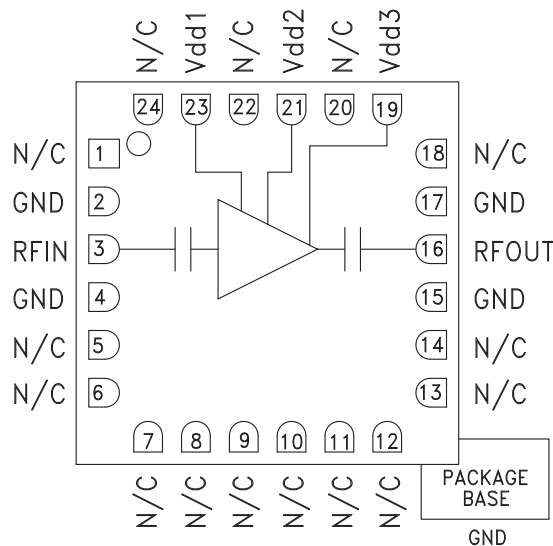
The HMC519LC4 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military & Space

### Features

- Noise Figure: 3.5 dB
- Gain: 14 dB
- Output IP3: +23 dBm
- Single Supply: +3V @ 75 mA
- 50 Ohm Matched Input/Output
- 24 Lead Ceramic 4x4mm SMT Package: 16mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC519LC4 is a high dynamic range GaAs PHEMT MMIC Low Noise Amplifier (LNA) housed in a leadless 4 x 4 mm ceramic surface mount package. The amplifier operates between 18 and 31 GHz, providing 14 dB of small signal gain, 3.5 dB noise figure and output IP3 of +23 dBm, while requiring only 75 mA from a +3V single supply. The P1dB output power of +11 dBm, enables the LNA to function as a LO driver for balanced, I/Q or image reject mixers. The HMC519LC4 also features I/Os that are DC blocked and internally matched to 50 Ohms, making it ideal for microwave radio and VSAT applications.

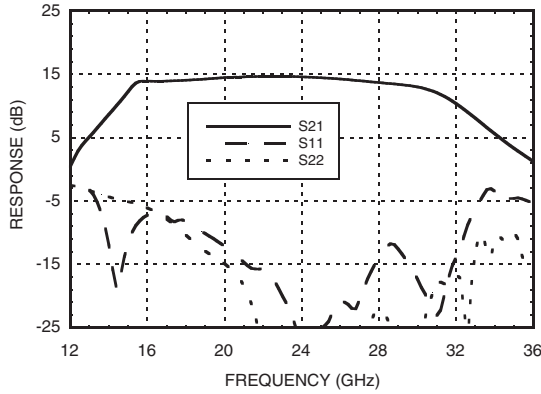
### Electrical Specifications, $T_A = +25^\circ C$ , Vdd 1, 2, 3 = +3V

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	18 - 28		28 - 31				GHz
Gain	11.4	14.4		10.2	13.2		dB
Gain Variation Over Temperature		0.016	0.026		0.016	0.026	dB/°C
Noise Figure		3.5	5.5		3	5	dB
Input Return Loss		15			17		dB
Output Return Loss		20			22		dB
Output Power for 1 dB Compression (P1dB)	8	11		9.2	12.2		dBm
Saturated Output Power (Psat)		14			15.4		dBm
Output Third Order Intercept (IP3)		23			24		dBm
Supply Current (Idd)		75	95		75	95	mA

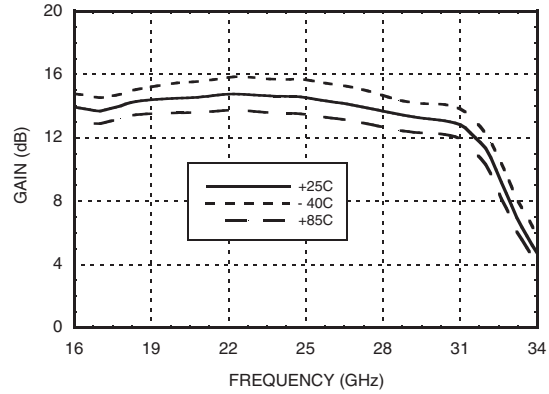


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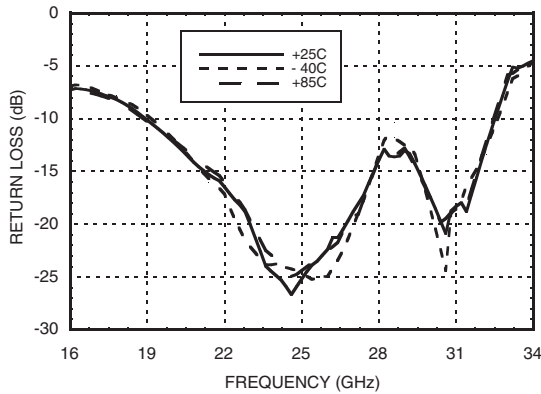
**Broadband Gain & Return Loss**



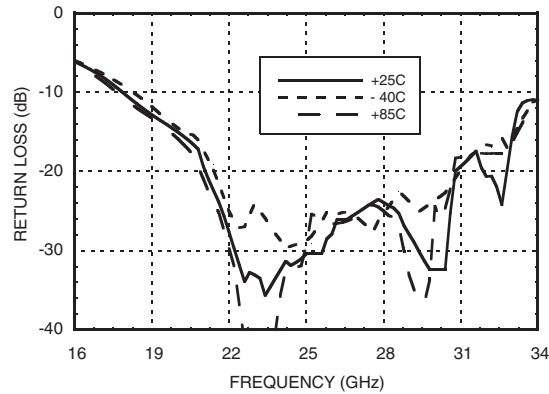
**Gain vs. Temperature**



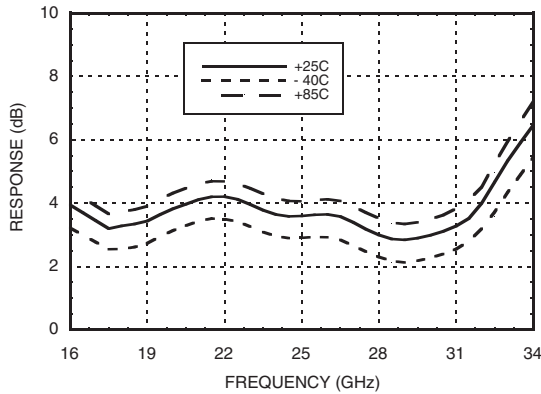
**Input Return Loss vs. Temperature**



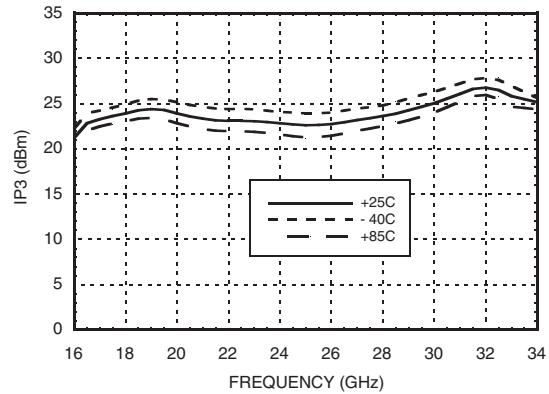
**Output Return Loss vs. Temperature**



**Noise Figure vs. Temperature**



**Output IP3 vs. Temperature**

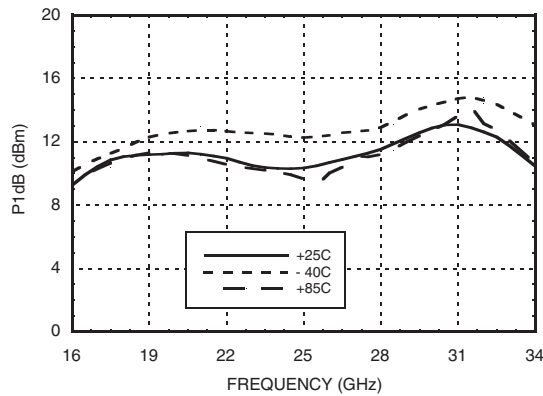


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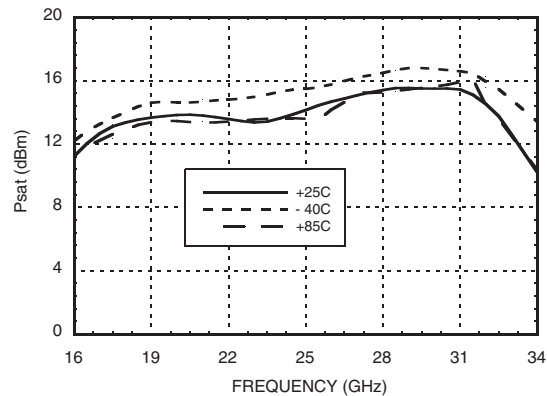


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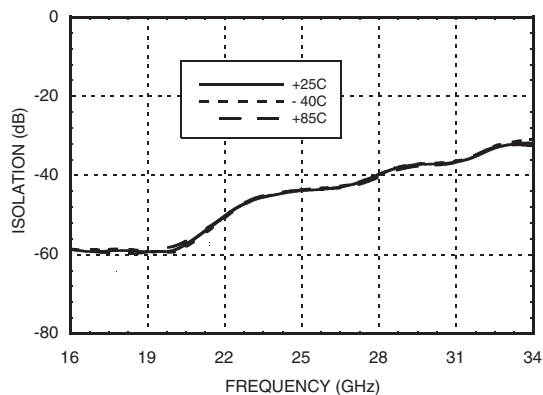
**P1dB vs. Temperature**



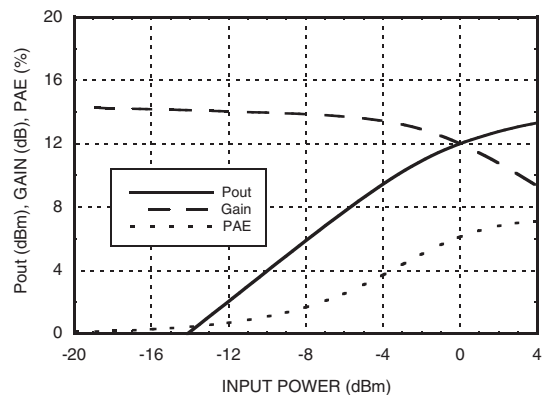
**Psat vs. Temperature**



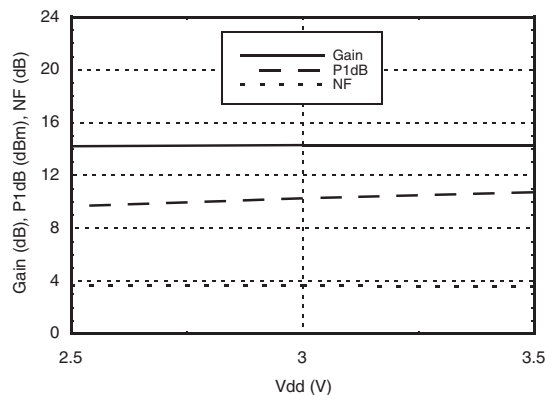
**Reverse Isolation vs. Temperature**



**Power Compression @ 24 GHz**



**Gain, Noise Figure & Power vs. Supply Voltage @ 24 GHz**





### GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2, Vdd3)	+3.5 Vdc
RF Input Power (RFIN)(Vdd = +3.0 Vdc)	+8 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 12 mW/°C above 85 °C)	1.08 W
Thermal Resistance (channel to package bottom)	83 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to 85 °C
ESD Sensitivity (HBM)	Class 1B

#### Typical Supply Current vs. Vdd

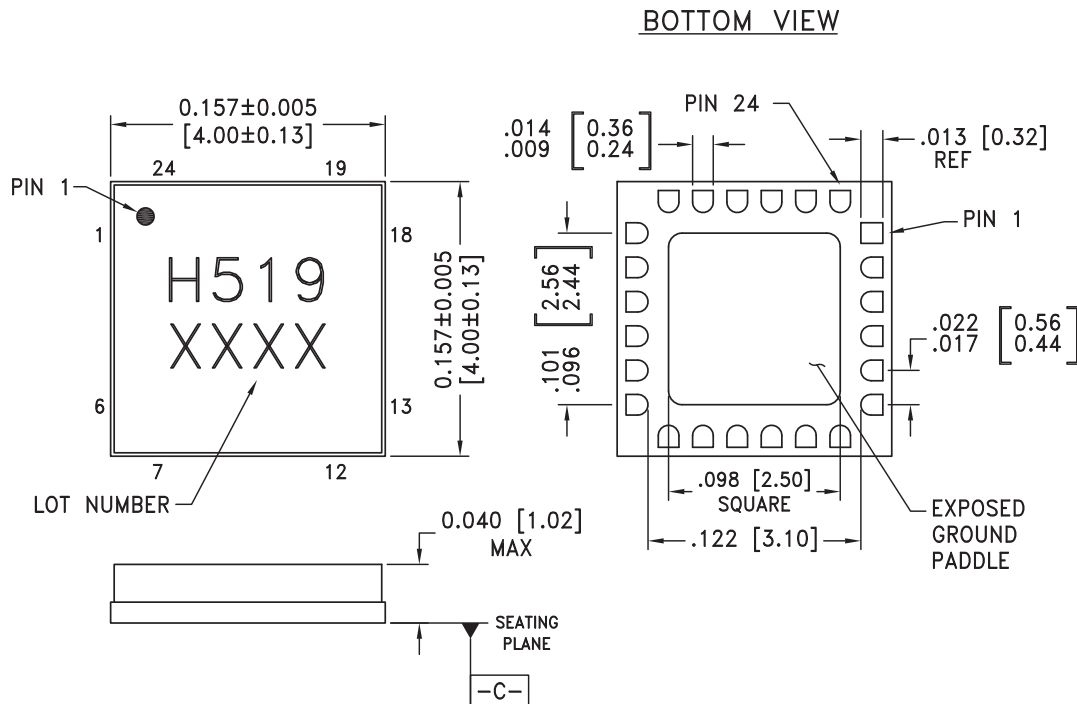
Vdd (Vdc)	Idd (mA)
2.5	72
3.0	75
3.5	78

Note: Amplifier will operate over full voltage ranges shown above.



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

#### Outline Drawing




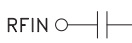
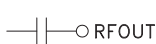
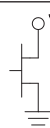
NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA.
2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER NICKEL.
3. DIMENSIONS ARE IN INCHES (MILLIMETERS).
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM  $\square-C$ .
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

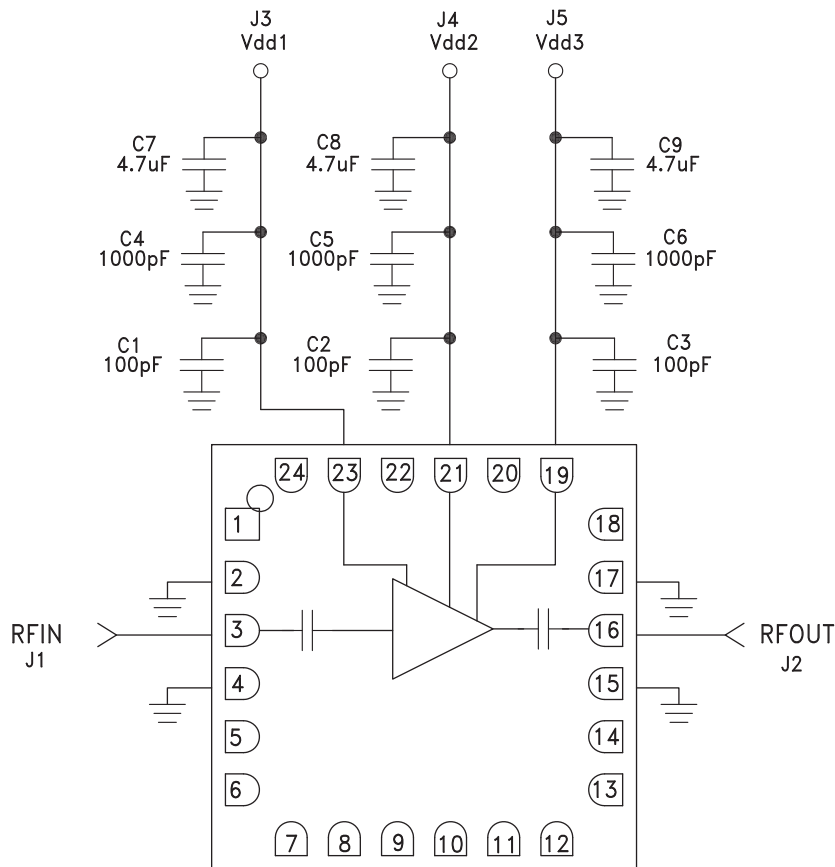


**GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz**

**Pad Descriptions**

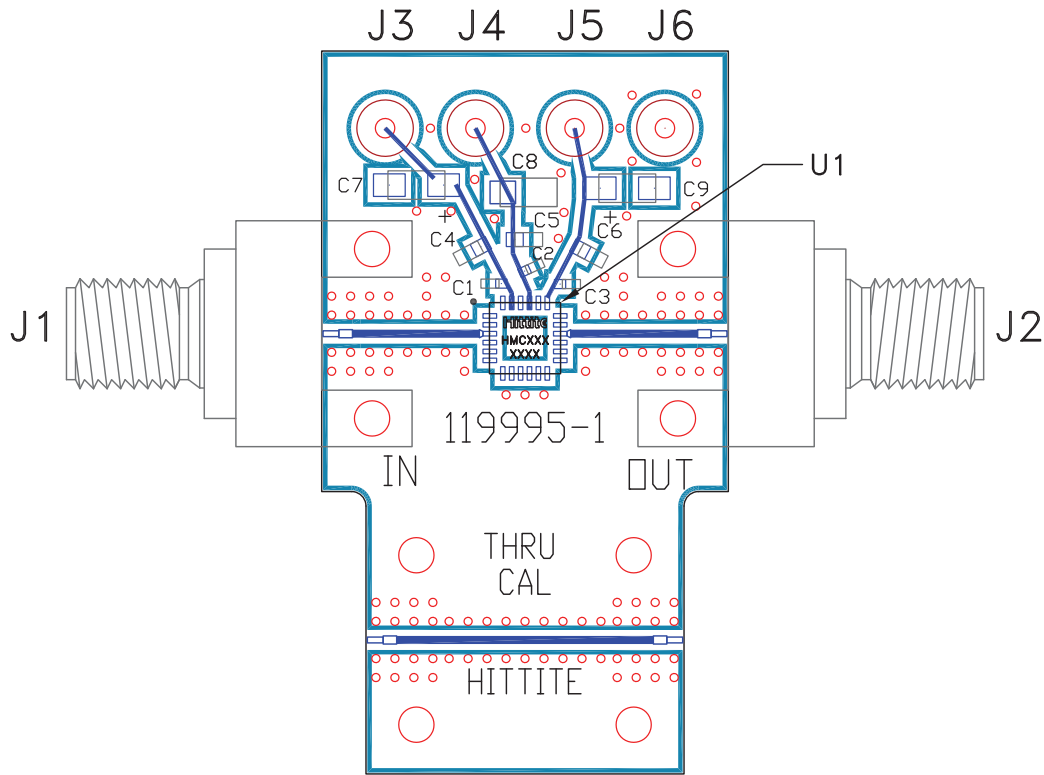
Pad Number	Function	Description	Interface Schematic
1, 5-14, 18, 20, 22, 24	N/C	Not Connected	
2, 4, 15, 17	GND	Package bottom has exposed metal paddle that must be connected to RF/DC ground.	
3	RFIN	This pad is AC coupled and matched to 50 Ohms	
16	RFOUT	This pad is AC coupled and matched to 50 Ohms	
19, 21, 23	Vdd3, Vdd2, Vdd1	Power Supply Voltage for the amplifier. See application circuit for required external components.	

**Application Circuit**





**Evaluation PCB**



**List of Material for Evaluation PCB 119667 [1]**

Item	Description
J1, J2	2.92mm PCB mount K-Connector
J3 - J6	DC Pin
C1, C2, C3	100pF Capacitor, 0402 Pkg.
C4, C5, C6	1000pF Capacitor, 0603 Pkg.
C7, C8, C9	4.7 $\mu$ F Capacitor, Tantalum
U1	HMC519LC4 Amplifier
PCB [2]	11995 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350.

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.